NSN 5961-01-359-8218

Diode Semiconductor Device - Page 1 of 1



View Online at https://aerobasegroup.com/nsn/5961-01-359-8218 **Inclosure Material:** Glass **Overall Length:** 0.205 inches **Overall Diameter:** 0.107 inches **Mounting Method: Terminal Semiconductor Material:** Silicon Voltage Rating In Volts Per Characteristic: 600.0 repetitive peak reverse voltage **Current Rating Per Characteristic:** 3.00 amperes forward current, average absolute **Special Features:** 1n5626 mtd to terminal lugs **Terminal Type And Quantity:** 2 uninsulated wire lead w/terminal lug Shelf Life: N/a **Unit Of Measure: Demilitarization:** No

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